



RF-BM-2652P4 and RF-BM-2652P4I CC2652P7
SimpleLink™ Multiprotocol 2.4 GHz Wireless Module
with Integrated Power Amplifier

Version 1.1

Shenzhen RF-star Technology Co., Ltd.

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1 Device Overview

1.1 Description

RF-BM-2652P4(I) is an RF module based on TI lower-power CC2652P7 SoC, which is a multiprotocol 2.4 GHz wireless module supporting Matter, Thread, Zigbee®, Bluetooth® 5.2 Low Energy, IEEE 802.15.4, IPv6-enabled smart objects (6LoWPAN), proprietary systems, including the TI 15.4-Stack (2.4 GHz), and concurrent multiprotocol through a Dynamic Multiprotocol Manager (DMM) driver. It integrates a 48 MHz crystal and a 32.768 kHz crystal, 704 kB of in-system Programmable Flash, 256 kB ROM, 8 kB of Cache SRAM, and 144 kB of ultra-low leakage SRAM. Its ARM® Cortex®-M4F core application processor can operate at an extremely low current at flexible power modes. And the module enables long-range and low-power applications using an integrated +20 dBm high-power amplifier with best-in-class transmit current consumption at 101 mA. It features a small size, robust connection distance, and rigid reliability. Optional antenna output modes (PCB, IPEX connector, and half-hole interface) make the module more convenient for application and development.

1.2 Key Features

- RF Features
 - Bluetooth® 5.2 Low Energy
 - Matter, ZigBee®, Thread
 - Proprietary systems
 - IEEE 802.15.4
 - IPv6-enabled smart objects (6LoWPAN)
 - SimpleLink™ TI 15.4-Stack (2.4 GHz)
 - Dynamic Multiprotocol Manager (DDM) driver
- TX power: up to +20 dBm with temperature compensation
- Excellent receiver sensitivity
 - -99 dBm for 802.15.4 (2.4 GHz)
 - -104 dBm for Bluetooth 125 kbps (LE coded PHY)
- Wide Operation Range
 - 1.8 V to 3.8 V single power supply
 - Operating temperature: -40 °C to +85 °C
 - Storage temperature: -40 °C to +125 °C
- Microcontroller
 - Powerful 48 MHz ARM® Cortex®-M4F processor
 - EEBMC CoreMark® score: 148
 - 2-pin cJTAG and JTAG debugging
 - Support OTA upgrade
- Memory
 - 704 kB of in-system programmable flash
 - 256 kB of ROM for protocols and library functions
 - 8 kB of cache SRAM (Alternatively available as general-purpose RAM)
 - 144 kB of ultra-low leakage SRAM. The SRAM is protected by parity to ensure high reliability of operation.
- Ultra-low power sensor controller with 4 kB of SRAM
 - Sample, store, and process sensor data
 - Operation independent from system CPU
 - Fast wake-up for low-power operation
- Rich Peripherals
 - Digital peripheral pins can be routed to 23 GPIOs
 - 4 × 32-bit or 8 × 16-bit general-purpose timers
 - 12-bit ADC, 200 ksamples/s, 8 channels
 - 2 × comparators
 - Programmable current source
 - 2 × UART

- 2 × SSI (SPI, Microwave, TI)
- I²C
- I²S
- Real-time clock (RTC)
- Integrated temperature and battery monitor
- Security Enablers
 - AES 128-bit and 256-bit Crypto accelerator
 - ECC and RSA public key hardware accelerator
 - SHA2 accelerator (full suite up to SHA-512)
 - True random number generator (TRNG)
- External system
 - On-chip buck DC/DC converter
- Dimension: 30.0 mm × 16.4 mm × 2.25 mm
- RF-BM-2652P4 certificate: FCC

1.3 Applications

- 2400 to 2480 MH ISM and SRD systems with down to 4 kHz of receive bandwidth
- Home and building automation
- Building security system
- HVAC system
- Gateway
- IP network camera
- Fire safety system
- Smart grid
- Automatic meter reading
- Industrial transport
- Wireless sensor networks
- Factory automation and control
- Wireless healthcare applications
- Energy harvesting applications
- Asset tracking and management
- Electronic Shelf Label (ESL)
- Wired networking
- Small business router
- Portable electronics
- Set-top box
- Connected peripherals
- Keyboard and keypads
- Home theater & entertainment
- Electronic and robotic toys
- Wearables

1.4 Functional Block Diagram

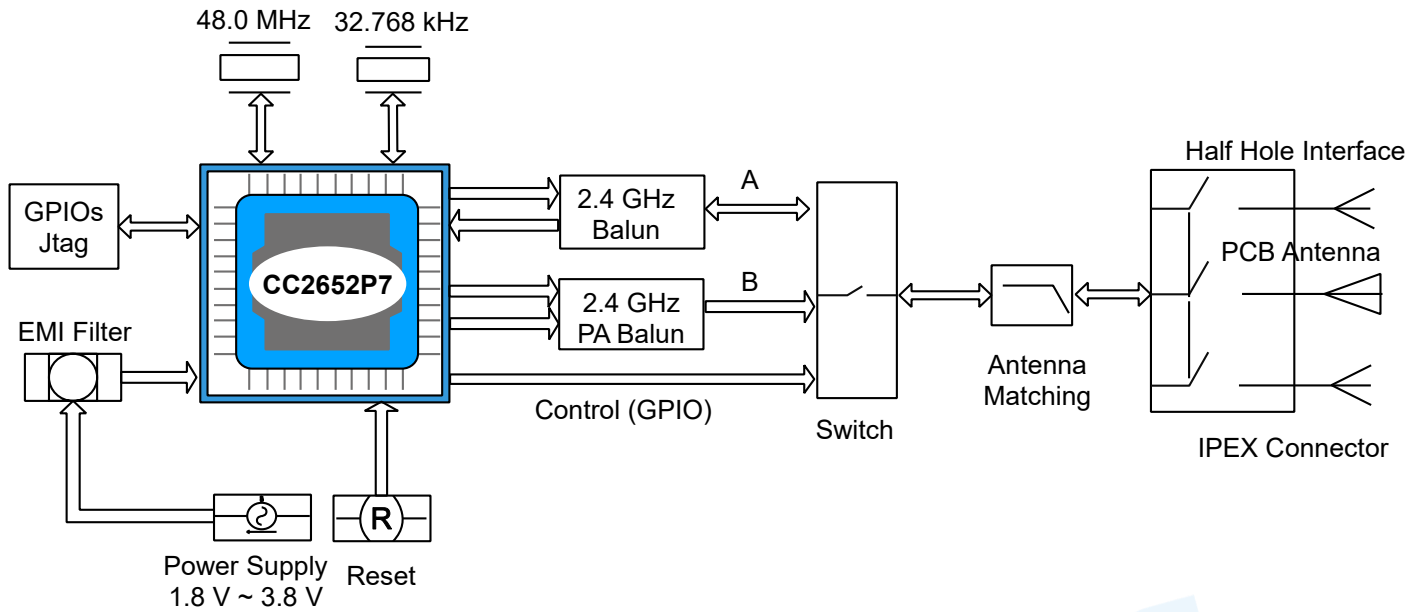


Figure 1. Functional Block Diagram of RF-BM-2652P4(I)

1.5 Part Number Conventions

The part numbers are of the form of RF-BM-2652P4(I) where the fields are defined as follows:

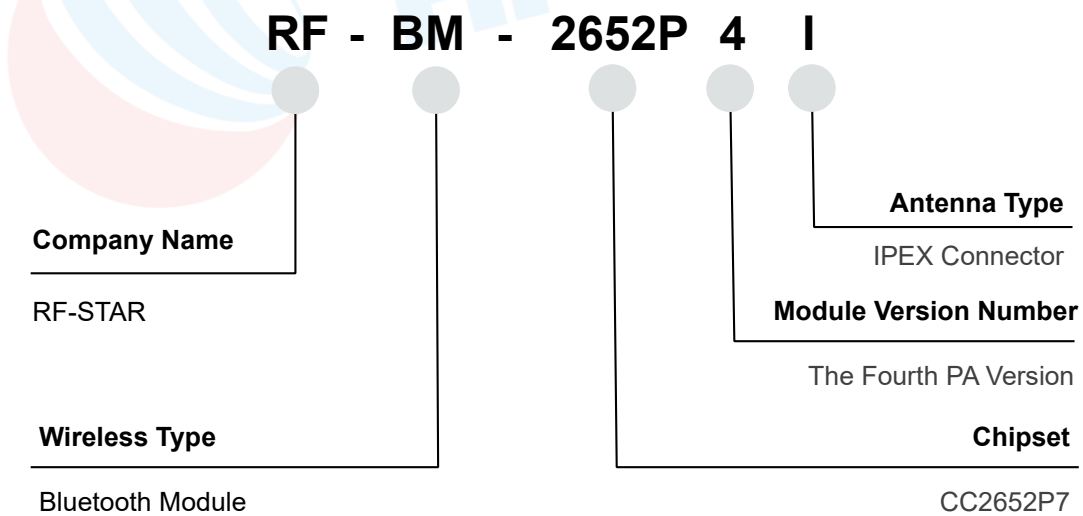


Figure 2. Part Number Conventions of RF-BM-2652P4(I)

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2 Module Configuration and Functions

2.1 Module Parameters

Table 1. Parameters of RF-BM-2652P4(I)

| | |
|------------------------|--|
| Chipset | CC2652P7 |
| Supply Power Voltage | 1.8 V ~ 3.8 V, 3.3 V is recommended |
| Frequency | 2402 MHz ~ 2480 MHz |
| Maximum Transmit Power | +20.0 dBm |
| Receiving Sensitivity | -99 dBm @ 802.15.4 (2.4 GHz) -104 dBm @ Bluetooth 125 kbps (LE Coded PHY) |
| GPIO | 23 |
| Flash | 704 kB |
| ROM | 256 kB |
| SRAM | 152 kB |
| Power Consumption | RX current: 6.4 mA TX current: 7.3 mA @ 0 dBm 9.7 mA @ 5 dBm 21 mA @ 10 dBm 101 mA @ 20 dBm MCU 48 MHz (CoreMark): 3.1 mA (65 μ A/MHz) Sensor Controller: 29.2 μ A @ Low Power-Mode, 2 MHz 799 μ A @ Active-Mode, 24 MHz Standby: 0.9 μ A Shutdown: 0.1 μ A |
| Support Protocol | Bluetooth 5.2 Low Energy, Matter, ZigBee, Thread, IEEE 802.15.4, 6LoWPAN, SimpleLink™ TI 15.4-stack, Proprietary systems |
| Crystal | 48 MHz, 32.768 kHz |
| Package | SMT packaging (1.27-mm half-hole pitch stamp stick) |
| Dimension | 30.0 mm × 16.4 mm × 2.25 mm |
| Type of Antenna | RF-BM-2652P4: PCB antenna RF-BM-2652P4I: IPEX connector, ANT pin |
| Operating Temperature | -40 °C ~ +85 °C |
| Storage Temperature | -40 °C ~ +125 °C |

2.2 Module Pin Diagram

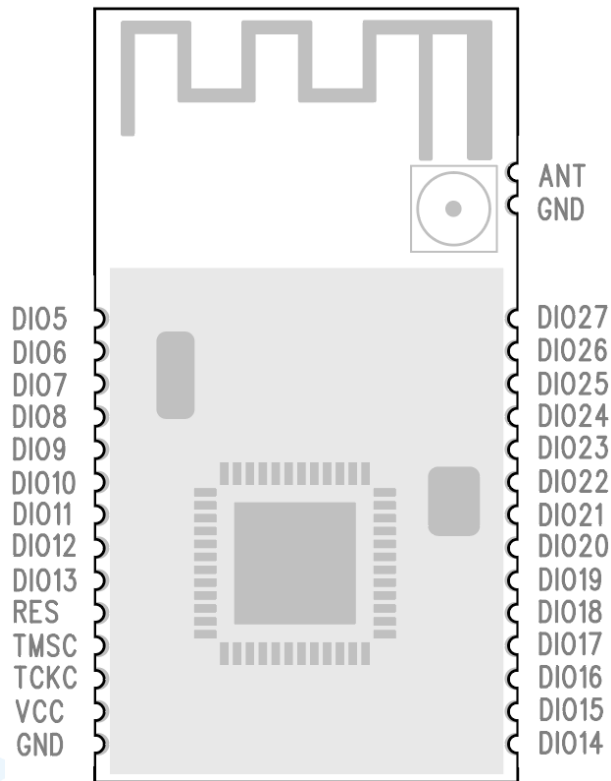


Figure 3. Pin Diagram of RF-BM-2652P4(I)

2.3 Pin Functions

Table 2. Pin Diagram of RF-BM-2652P4(I)

| Pin | Name | Chip Pin | Function | Description |
|-----|-----------|-----------|----------|-------------------------------------|
| 1 | DIO5 | DIO_5 | Digital | GPIO, high-drive capability |
| 2 | DIO6 | DIO_6 | Digital | GPIO, high-drive capability |
| 3 | DIO7 | DIO_7 | Digital | GPIO, high-drive capability |
| 4 | DIO8 | DIO_8 | Digital | GPIO |
| 5 | DIO9 | DIO_9 | Digital | GPIO |
| 6 | DIO10 | DIO_10 | Digital | GPIO |
| 7 | DIO11 | DIO_11 | Digital | GPIO |
| 8 | DIO12 | DIO_12 | Digital | GPIO |
| 9 | DIO13 | DIO_13 | Digital | GPIO |
| 10 | RES | RESET_N | Digital | Reset, active low. Internal pullup. |
| 11 | JTAG_TMSC | JTAG_TMSC | Digital | JTAG TMSC, high-drive capability |
| 12 | JTAG_TCKC | JTAG_TCKC | Digital | JTAG TCKC |

| | | | | |
|----|-------|--------|-------------------|---|
| 13 | VCC | VCC | - | Power supply: 1.8 V ~ 3.8 V, recommended to 3.3 V |
| 14 | GND | GND | Ground | Ground |
| 15 | DIO14 | DIO_14 | Digital | GPIO |
| 16 | DIO15 | DIO_15 | Digital | GPIO |
| 17 | DIO16 | DIO_16 | Digital | GPIO, JTAG_TDO, high-drive capability |
| 18 | DIO17 | DIO_17 | Digital | GPIO, JTAG_TDI, high-drive capability |
| 19 | DIO18 | DIO_18 | Digital | GPIO |
| 20 | DIO19 | DIO_19 | Digital | GPIO |
| 21 | DIO20 | DIO_20 | Digital | GPIO |
| 22 | DIO21 | DIO_21 | Digital | GPIO |
| 23 | DIO22 | DIO_22 | Digital | GPIO |
| 24 | DIO23 | DIO_23 | Digital or Analog | GPIO, analog capability |
| 25 | DIO24 | DIO_24 | Digital or Analog | GPIO, analog capability |
| 26 | DIO25 | DIO_25 | Digital or Analog | GPIO, analog capability |
| 27 | DIO26 | DIO_26 | Digital or Analog | GPIO, analog capability |
| 28 | DIO27 | DIO_27 | Digital or Analog | GPIO, analog capability |
| 29 | GND | GND | Ground | Ground |
| 30 | ANT | | - | External antenna interface |

3 Specifications

3.1 Recommended Operating Conditions

Functional operation does not guarantee performance beyond the limits of the conditional parameter values in the table below. Long-term work beyond this limit will affect the reliability of the module more or less.

Table 3. Recommended Operating Conditions of RF-BM-2652P4(I)

| Items | Condition | Min. | Typ. | Max. | Unit |
|--------------------------|-----------|------|------|------|------|
| Operating Supply Voltage | / | 1.8 | 3.3 | 3.8 | V |
| Operating Temperature | / | -40 | +25 | +85 | °C |

3.2 Handling Ratings

Table 4. Handling Ratings of RF-BM-2652P4(I)

| Items | Condition | Min. | Typ. | Max. | Unit |
|----------------------------|-----------|------|-------|------|------|
| Storage Temperature | Tstg | -40 | +25 | +125 | °C |
| Human Body Model | HBM | | ±2000 | | V |
| Moisture Sensitivity Level | | | 3 | | |
| Charged Device Model | | | ±500 | | V |

3.3 PA Output Control

The module's high transmit power (>5 dBm) is achieved by controlling the outputs of DIO28 and DIO29 to switch the radio frequency switch and then enable the PA (HIGH POWER).

As shown in Table 3, when DIO28 outputs a low level and DIO29 outputs a high level, HIGH PA is turned on, and the module RF can output a transmit power greater than +5 dBm, with a maximum of +20 dBm.

When DIO28 outputs a high level and DIO29 outputs a low level, HIGH PA is turned off and the maximum transmit power of the module can only be +5 dBm.

Table 3. RF Control Truth Table

| Power | DIO28 (Output) | DIO29 (Output) |
|------------------------|----------------|----------------|
| +5 dBm ~ + 20 dBm (PA) | 0 | 1 |
| < 5 dBm | 1 | 0 |

4 Application, Implementation, and Layout

4.1 Module Photos

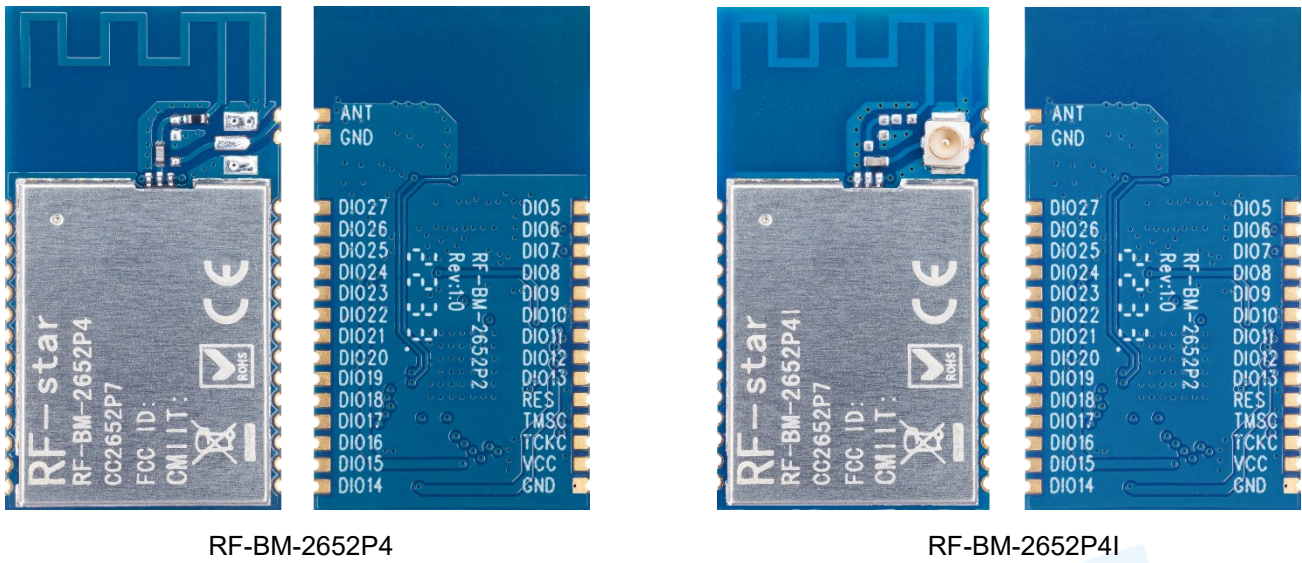


Figure 3. Photos of RF-BM-2652P4(I)

4.2 Recommended PCB Footprint

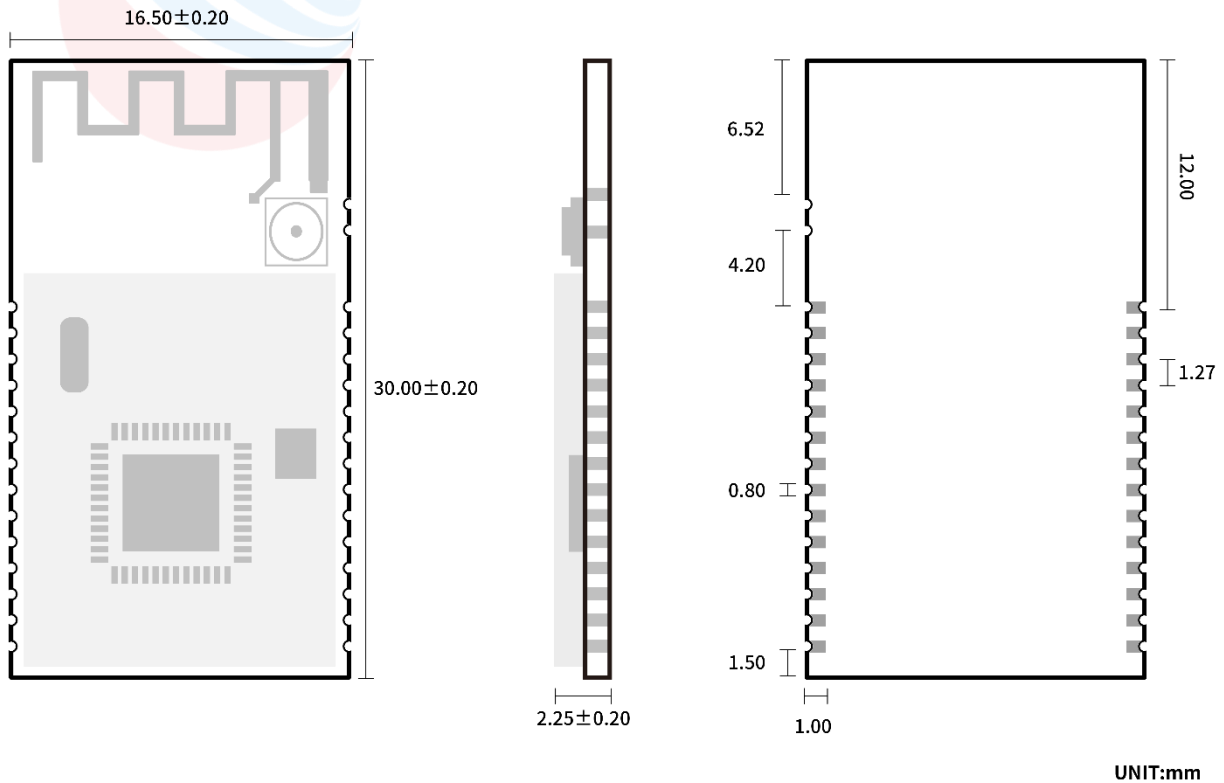


Figure 4. Recommended PCB Footprint of RF-BM-2652P4(I)

4.3 Schematic Diagram

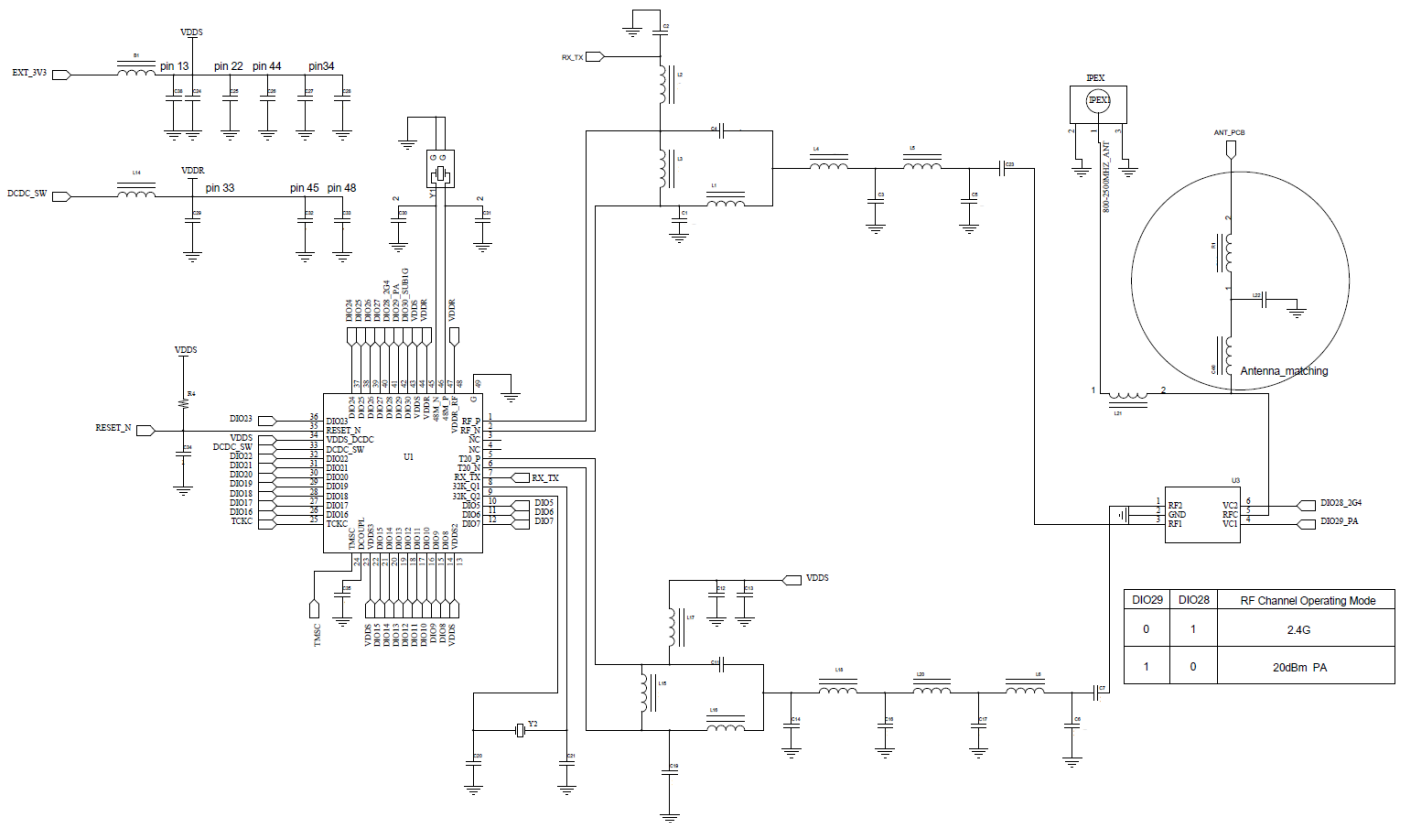


Figure 5. Schematic Diagram of RF-BM-2652P4(I)

4.4 Reference Design

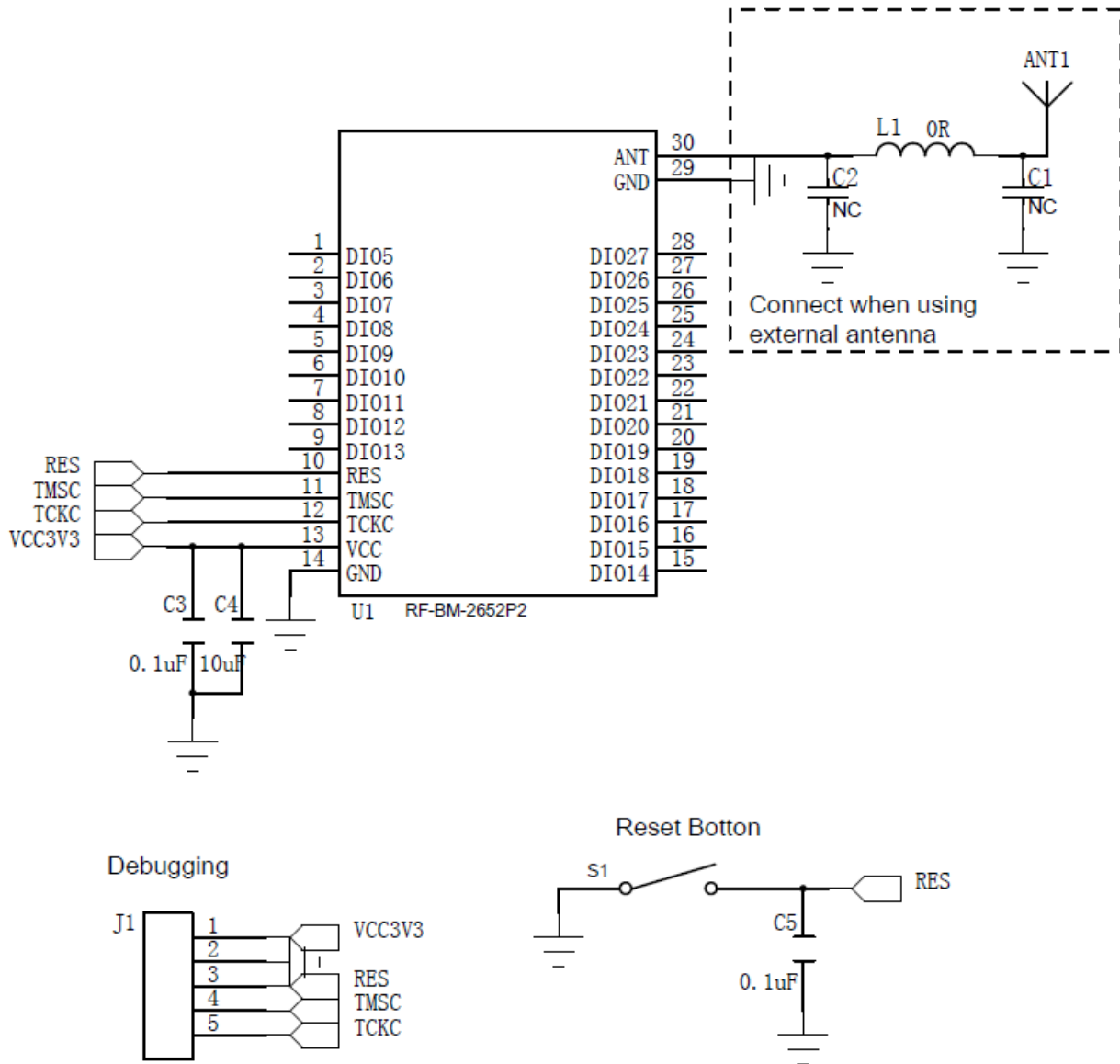


Figure 5. Reference Design of RF-BM-2652P4(I)

4.5 Antenna

4.5.1 Antenna Design Recommendation

1. The antenna installation structure has a great influence on the module performance. It is necessary to ensure that the antenna is exposed and preferably vertically upward. When the module is installed inside of the case, a high-quality antenna extension wire can be used to extend the antenna to the outside of the case.
2. The antenna must not be installed inside the metal case, which will cause the transmission distance to be greatly

weakened.

3. The recommendation of antenna layout.

The inverted-F antenna position on PCB is free-space electromagnetic radiation. The location and layout of the antenna are key factors to increase the data rate and transmission range.

Therefore, the layout of the module antenna location and routing is recommended as follows:

- (1) Place the antenna on the edge (corner) of the PCB.
- (2) Make sure that there is no signal line or copper foil in each layer below the antenna.
- (3) It is best to hollow out the antenna position in the following figure to ensure that the S11 of the module is minimally affected.

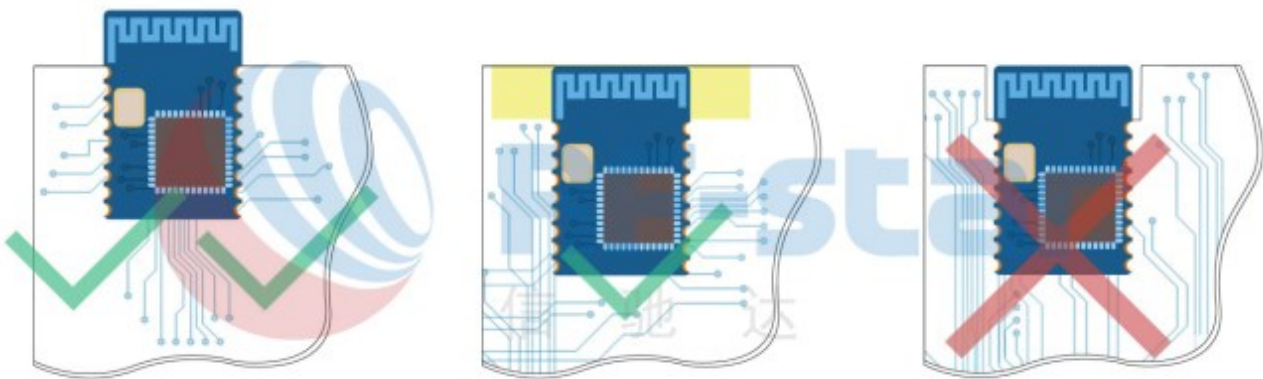


Figure 4. Recommendation of Antenna Layout

Note: The hollow-out position is based on the antenna used.

4.5.2 Antenna Output Mode Modification

This module has three antenna output modes, namely PCB, IPEX connector and stamp RF ANT interface output (RF ANT pin, see the pin definition table for details).

As shown in the figure below, the components in the red box use PCB antenna (RF-BM-2652P4). If you want to switch to IPEX connector (RF-BM-2652P4I) or ANT pin external antenna test effect, you can change the component in the red box by rotating it 90 degrees and solder it to the green box position (**Note: This operation method is not recommended because the internal antenna matching circuit components of the RF-BM-2652P4 and RF-BM-2652P4I modules are different, and the actual output power directly changed in this way will be biased. weak**).

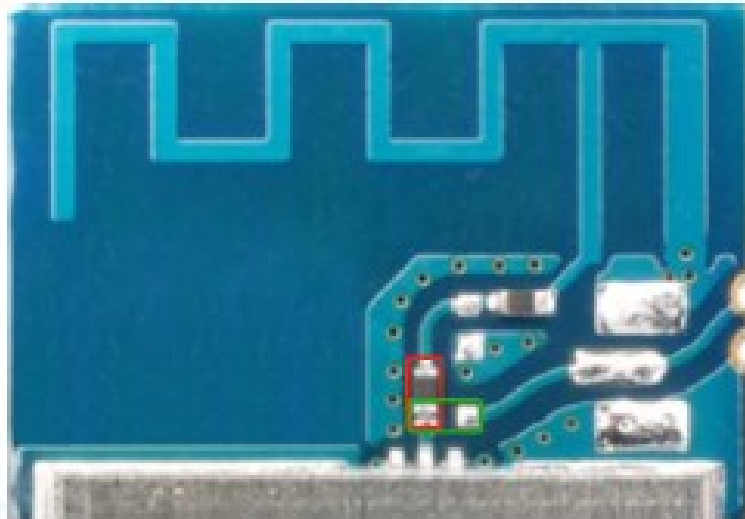


Figure 5. Antenna Output Mode Modification of RF-BM-2652P4(I)

4.5.3 External Antenna Design Recommendation of the Half-Hole ANT Pin

1. A Π -type matching circuit is reserved for the antenna, and $50\ \Omega$ impedance control is performed on the RF traces. The traces are as short as possible, and 135° or arc traces are used as much as possible. No vias are used to change layers. More GND vias are placed around the RF traces.

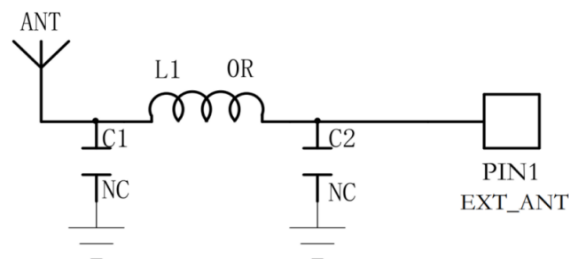


Figure 6. Reference Design of the External Antenna

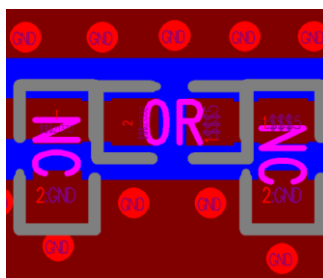


Figure 7. Reference Design of the External Antenna Traces

2. The RF trace width and copper-clad spacing can be calculated by SI9000 software, and the impedance is controlled to $50\ \Omega$ according to the actual board thickness, number of layers, plate, dielectric thickness, dielectric constant, copper thickness, line width, line spacing, and solder mask thickness.

Example: FR4 is a double-layer board with a thickness of 1.0 mm. Through calculation, the width of the trace is 0.8254 mm, and the spacing between traces and copper is 0.22 mm.

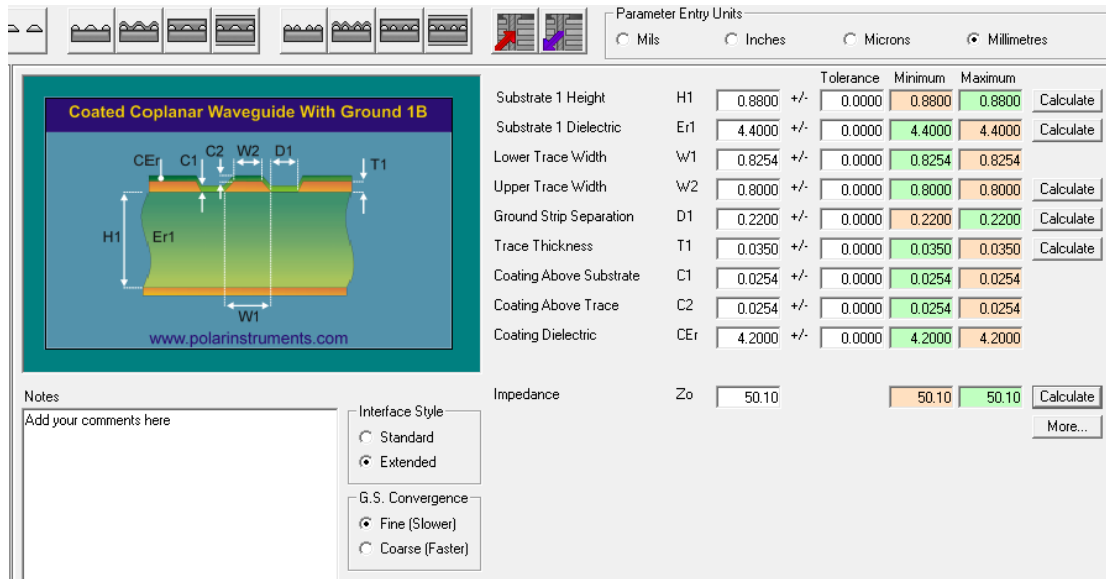


Figure 8. SI9000 Impedance Calculation Diagram

4.5.4 IPEX Connector Specification

RF-BM-2652P4I module is integrated the IPEX version 1 antenna seat, the specification of the antenna seat is as follows:

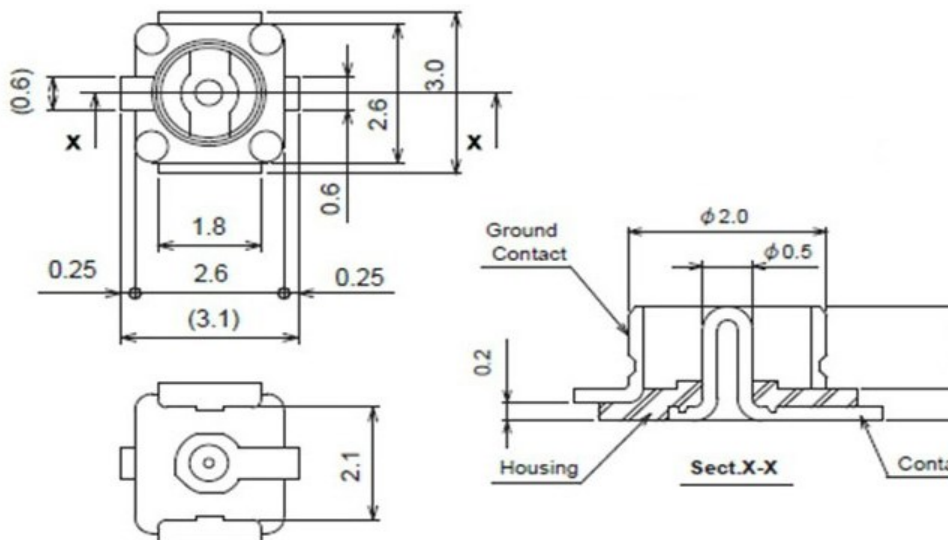


Figure 9. Specification of Antenna Seat

The specification of the IPEX wire end is as follows:

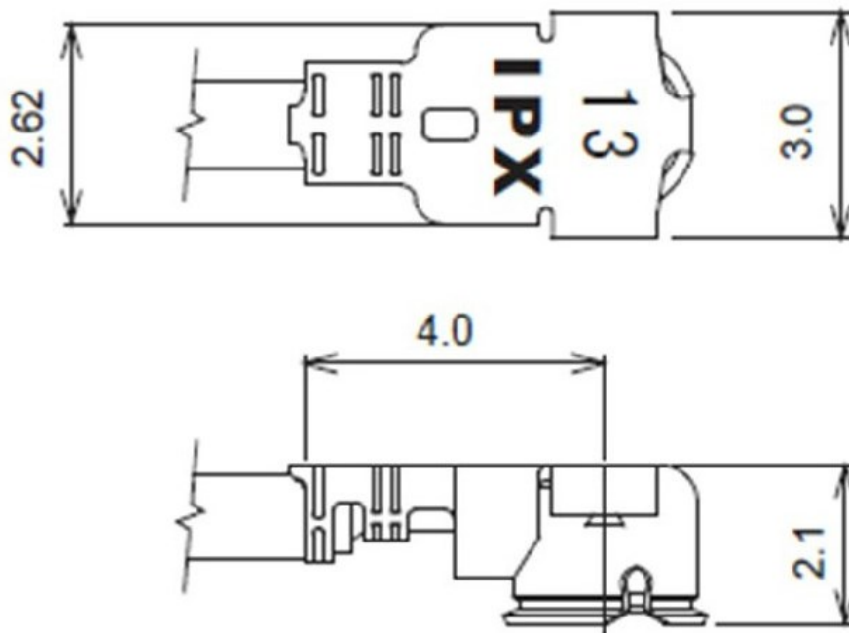


Figure 10. Specification of IPEX Wire

4.6 Basic Operation of Hardware Design

1. It is recommended to offer the module a DC stabilized power supply, a tiny power supply ripple coefficient, and reliable ground. Please pay attention to the correct connection between the positive and negative poles of the power supply. Otherwise, the reverse connection may cause permanent damage to the module.
2. Please ensure the supply voltage is between the recommended values. The module will be permanently damaged if the voltage exceeds the maximum value. Please ensure a stable power supply and no frequently fluctuating voltage.
3. When designing the power supply circuit for the module, it is recommended to reserve more than 30% of the margin, which is beneficial to the long-term stable operation of the whole machine. The module should be far away from the power electromagnetic, transformer, high-frequency wiring, and other parts with large electromagnetic interference.
4. The bottom of the module should avoid high-frequency digital routing, high-frequency analog routing, and power routing. If it has to route the wire on the bottom of the module, for example, it is assumed that the module is soldered to the Top Layer, the copper must be spread on the connection part of the top layer and the module, and be close to the digital part of the module and routed in the Bottom Layer (all copper is well-grounded).
5. Assuming that the module is soldered or placed in the Top Layer, it is also wrong to randomly route the Bottom Layer or other layers, which will affect the spurs and receiving sensitivity of the module to some degree.
6. Assuming that there are devices with large electromagnetic interference around the module, which will greatly affect the module performance. It is recommended to stay away from the module according to the strength of the

interference. If circumstances permit, appropriate isolation and shielding can be done.

7. Assuming that there are routings of large electromagnetic interference around the module (high-frequency digital, high-frequency analog, power routings), which will also greatly affect the module performance. It is recommended to stay away from the module according to the strength of the interference. If circumstances permit, appropriate isolation and shielding can be done.
8. It is recommended to stay away from the devices whose TTL protocol is the same 2.4 GHz physical layer, for example, USB 3.0.

4.7 Trouble Shooting

4.7.1 Unsatisfactory Transmission Distance

1. When there is a linear communication obstacle, the communication distance will be correspondingly weakened. Temperature, humidity, and co-channel interference will lead to an increase in the communication packet loss rate. The performances of ground absorption and reflection of radio waves will be poor when the module is tested close to the ground.
2. Seawater has a strong ability to absorb radio waves, so the test results by the seaside are poor.
3. The signal attenuation will be very obvious if there is metal near the antenna or if the module is placed inside the metal shell.
4. The incorrect power register set or the high data rate in the open air may shorten the communication distance. The higher the data rate, the closer the distance.
5. The low voltage of the power supply is lower than the recommended value at ambient temperature, and the lower the voltage, the smaller the power is.
6. The unmatched antennas and modules or the poor quality of antenna will affect the communication distance.

4.7.2 Vulnerable Module

1. Please ensure the supply voltage is between the recommended values. The module will be permanently damaged if the voltage exceeds the maximum value. Please ensure a stable power supply and no frequently fluctuating voltage.
2. Please ensure the anti-static installation and the electrostatic sensitivity of high-frequency devices.
3. Due to some humidity-sensitive components, please ensure the suitable humidity during installation and application. If there is no special demand, it is not recommended to use at too high or too low temperature.

4.7.3 High Bit Error Rate

1. There are co-channel signal interferences nearby. It is recommended to be away from the interference sources or modify the frequency and channel to avoid interferences.

2. The unsatisfactory power supply may also cause garbled. It is necessary to ensure the power supply's reliability.
3. If the extension wire or feeder wire is of poor quality or too long, the bit error rate will be high.

4.8 Electrostatics Discharge Warnings

The module will be damaged by the discharge of static. RF-star suggests that all modules should follow the 3 precautions below:

1. According to the anti-static measures, bare hands are not allowed to touch modules.
2. Modules must be placed in anti-static areas.
3. Take the anti-static circuitry (when inputting HV or VHF) into consideration in product design.

Static may result in the degradation in performance of the module, even causing failure.

4.9 Soldering and Reflow Condition

1. Heating method: Conventional Convection or IR/convection.
2. Solder paste composition: Sn96.5/Ag3.0/Cu0.5
3. Allowable reflow soldering times: 2 times based on the following reflow soldering profile.
4. Temperature profile: Reflow soldering shall be done according to the following temperature profile.
5. Peak temperature: 245 °C.

Table 5. Temperature Table of Soldering and Reflow

| Profile Feature | Sn-Pb Assembly | Pb-Free Assembly |
|--|-----------------|------------------------|
| Solder Paste | Sn63 / Pb37 | Sn96.5 / Ag3.0 / Cu0.5 |
| Min. Preheating Temperature (T_{min}) | 100 °C | 150 °C |
| Max. Preheating Temperature (T_{max}) | 150 °C | 200 °C |
| Preheating Time (T_{min} to T_{max}) (t_1) | 60 s ~ 120 s | 60 s ~ 120 s |
| Average Ascend Rate (T_{max} to T_p) | Max. 3 °C/s | Max. 3 °C/s |
| Liquid Temperature (T_L) | 183 °C | 217 °C |
| Time above Liquidus (t_L) | 60 s ~ 90 s | 30 s ~ 90 s |
| Peak Temperature (T_p) | 220 °C ~ 235 °C | 230 °C ~ 250 °C |
| Average Descend Rate (T_p to T_{max}) | Max. 6 °C/s | Max. 6 °C/s |
| Time from 25 °C to Peak Temperature (t_2) | Max. 6 minutes | Max. 8 minutes |
| Time of Soldering Zone (t_p) | 20±10 s | 20±10 s |

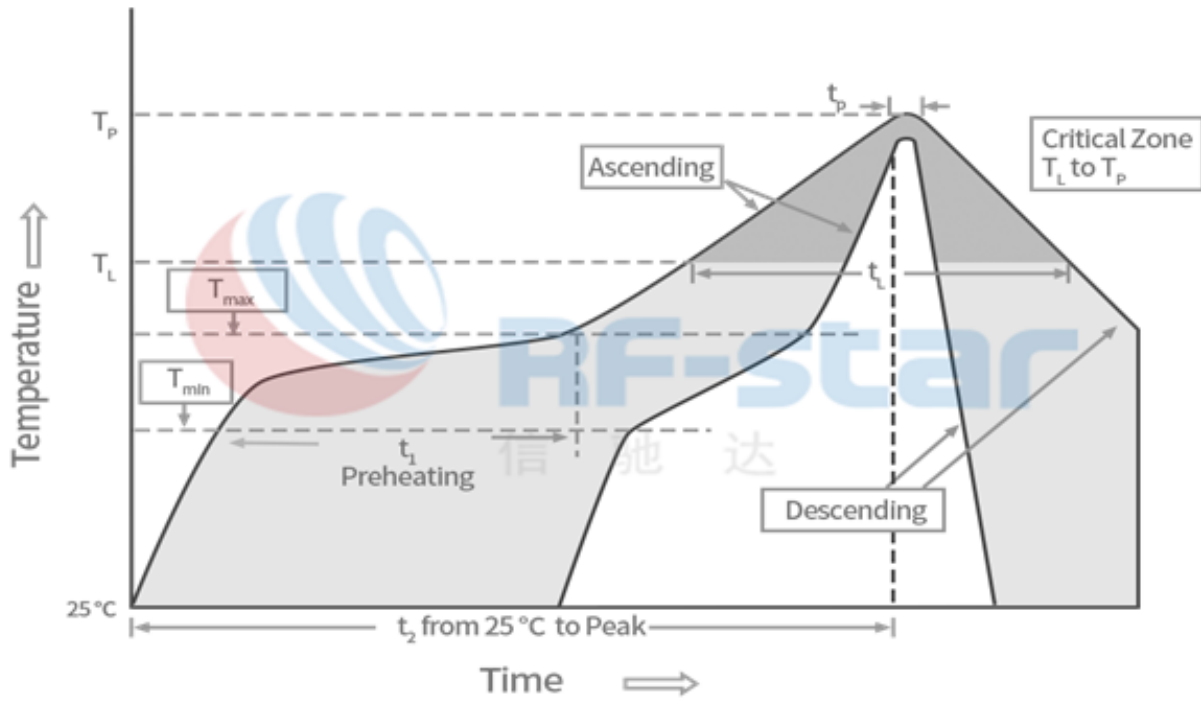


Figure 11. Recommended Reflow for Lead-Free Solder

5 Optional Package Specification

The default package method is **by tray**. If you need the modules to be shipped by tape & reel, pls contact us in advance.

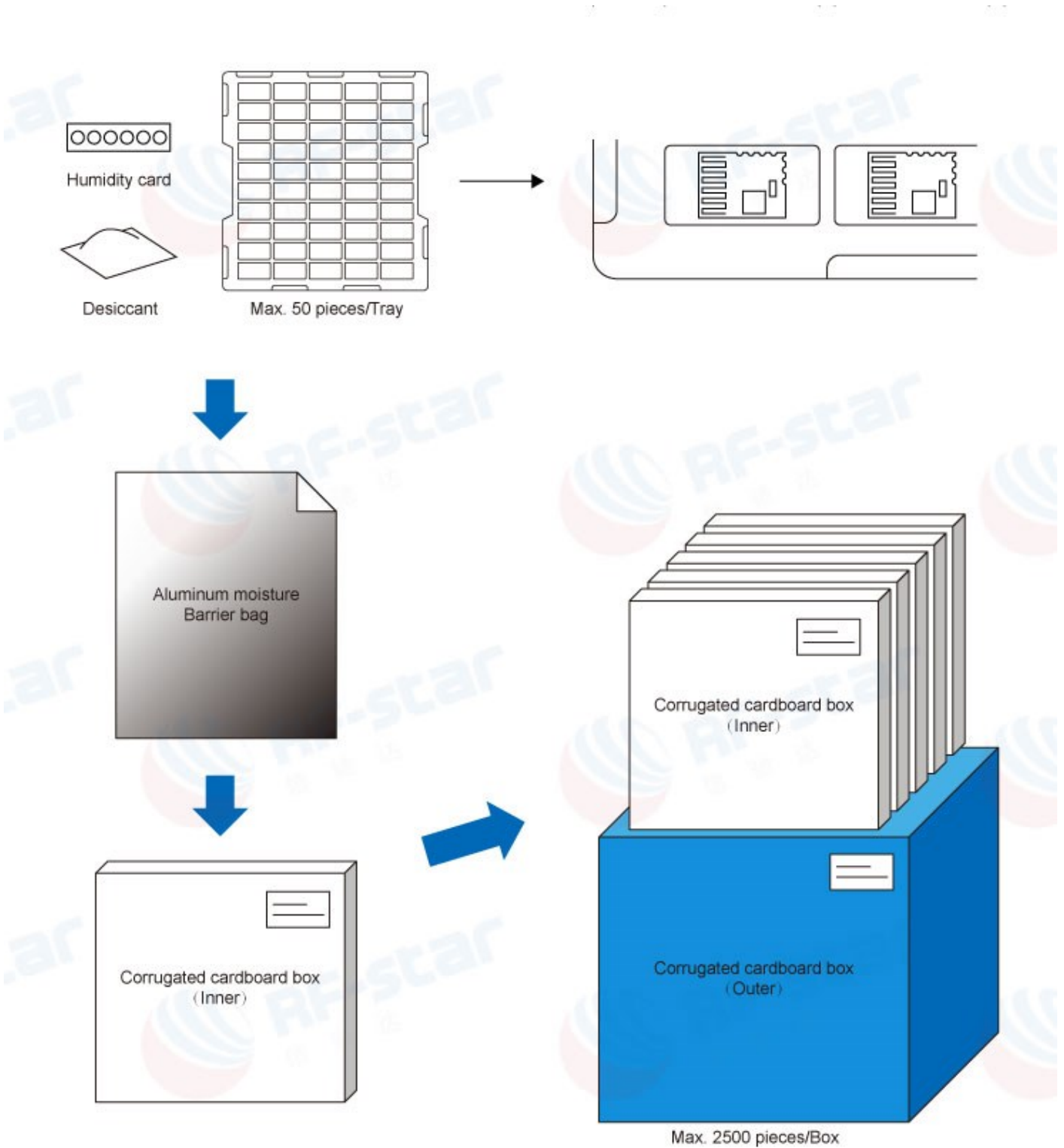


Figure 12. Default Package by Tray

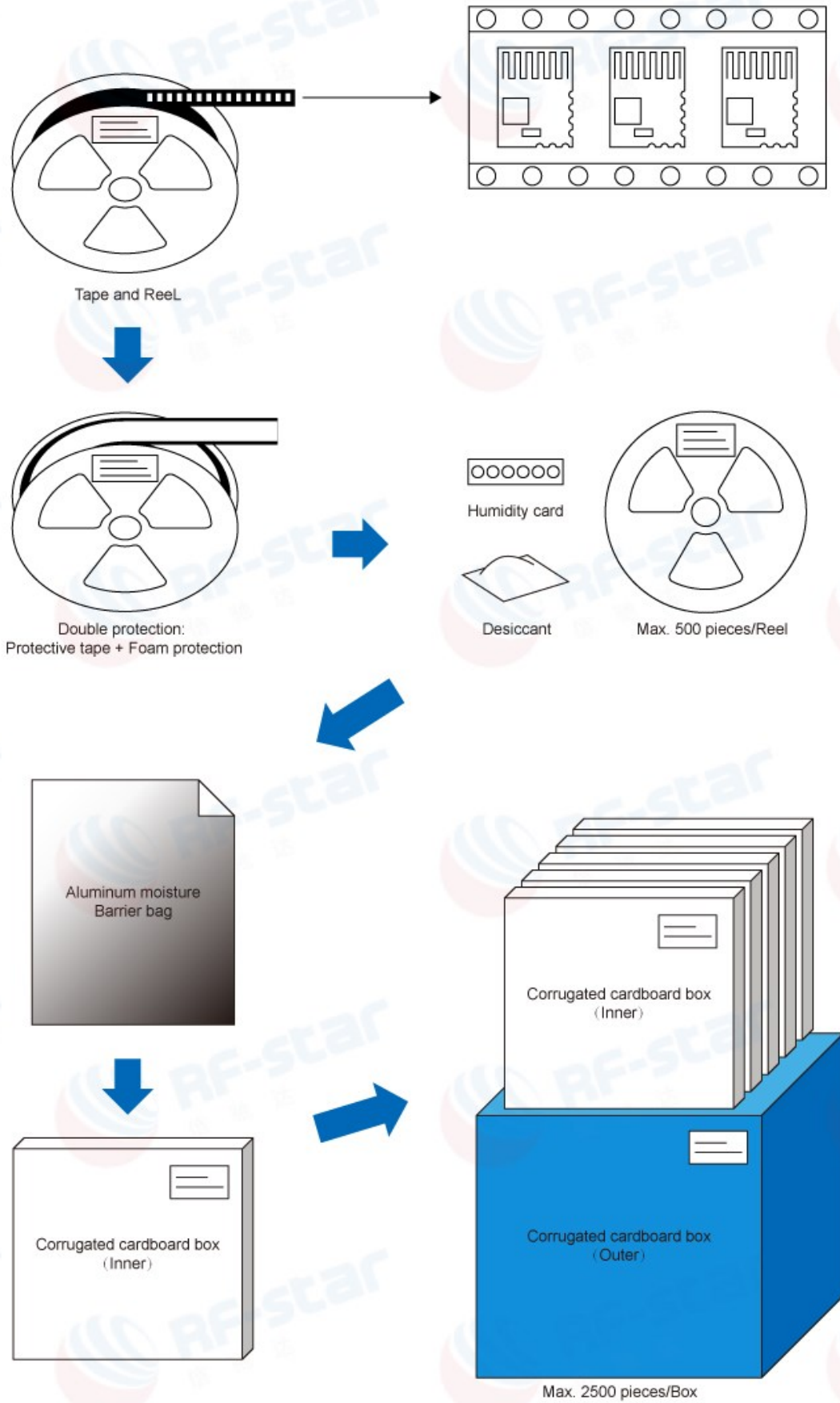


Figure 13. Package by Tape & Reel

6 Certificate

6.1 FCC

This device complies with part 15 of the FCC Rules. Operation is subject to the following two conditions: (1) This device may not cause harmful interference, and (2) this device must accept any interference received, including interference that may cause undesired operation.

FCC ID: 2ABN2-2652P4

TCB

GRANT OF EQUIPMENT AUTHORIZATION
 Certification
 Issued Under the Authority of the
 Federal Communications Commission
 By:

TCB

SOS North America, Inc.
 620 Old Peachtree Road NW Suite 100
 Suwanee, GA 30024

ShenZhen RF-STAR Technology CO.,LTD
 ZF,BLDG.8Zone A,BaoAn Internet Industry Base,
 BaoYuan Road,XIXiang, BaoAn DIST,
 ShenZhen,
 China

Attention: Aree woo

Date of Grant: 01/04/2024
 Application Dated: 01/04/2024

NOT TRANSFERABLE
 EQUIPMENT AUTHORIZATION is hereby issued to the named GRANTEE, and is
 VALID ONLY for the equipment identified hereon for use under the Commission's
 Rules and Regulations listed below.

FCC IDENTIFIER: 2ABN2-2652P4
 Name of Grantee: ShenZhen RF-STAR Technology CO.,LTD
 Equipment Class: Digital Transmission System
 Notes: Multiprotocol 2.4 GHz Wireless Module
 Modular Type: Single Modular

| Grant Notes | FCC Rule Parts | Frequency Range (MHz) | Output Watts | Frequency Tolerance | Emission Designator |
|-------------|----------------|-----------------------|--------------|---------------------|---------------------|
| | 15C | 2402.0 - 2489.0 | 0.0883 | | |
| | 15C | 2405.0 - 2489.0 | 0.0883 | | |

Power Output listed is conducted. Single Modular Approval. The antenna(s) used for this transmitter must be installed to provide a separation distance of at least 20 cm from all persons. Co-location of this module with other transmitters that operate simultaneously are required to be evaluated using the FCC multi-transmitter procedures. End-Users must be provided with transmitter operation conditions for satisfying RF exposure compliance. OEM integrators must ensure that the end user has no manual instructions to remove or install this module. For mobile and fixed operating configurations, the antenna gain, including cable loss, must not exceed 2.72 dBi for satisfying RF exposure compliance according to as defined in 2.1091. The host integrator must follow the integration instructions provided by the module manufacturer and ensure that the composite system and product complies with the FCC requirements by a technical assessment or evaluation to the FCC rules and to KDB Publication 996369. The module grantee is responsible for providing the documentation to the system integrator on restrictions of use, for continuing compliance of the module. The host integrator installing this module into their product must ensure that the final composite product complies with the FCC requirements by a technical assessment or evaluation to the FCC rules, including the transmitter operation and should refer to guidance in KDB 996369.

Figure 14. FCC certificate of RF-BM-2652P4

7 Revision History

| Date | Version No. | Description |
|------------|-------------|--|
| 2022.12.12 | V1.0 | The initial version is released. |
| 2023.05.25 | V1.0 | Update MSL level. Update the Shenzhen office address. |
| 2024.01.23 | V1.1 | Update the Recommended PCB Footprint of RF-BM-2652P4(I). Update the Antenna Output Mode Modification. Add FCC certificate. |

Note:

1. The document will be optimized and updated from time to time. Before using this document, please make sure it is the latest version.
2. To obtain the latest document, please download it from the official website: www.rfstariot.com and www.szrfstar.com.



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